

VERSION WITH MARKINGS TO SHOW CHANGES MADE

IN THE CLAIMS:

Please amend the claims as follows:

27. (Amended) A semiconductor element according to [any one of claims 25 and 26] claim 25, wherein said outer circumferential negative electrode is formed to have a height at least equal to a height of a light-emitting layer on a side of at least one side wall of said light-emitting layer.